

FAIRCHILD

SEMICONDUCTOR

March 1994 Revised November 1999 '4ABT240 Octal Buffer/Line Driver with 3-STATE Outputs

74ABT240 Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

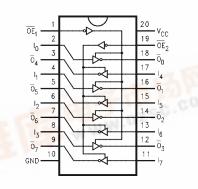
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT240CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT240CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT240CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT240CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description	
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output	
0048	Enable Inputs	
I ₀ –I ₇	Inputs	
$\overline{O}_0 - \overline{O}_7$	Outputs	

Truth Tables

Inp	outs	Outputs			
OE ₁	۱ _n	(Pins 12, 14, 16, 18)			
L	L	н			
L	н	···			
Н	Х	Z			
Inp	outs	Outputs (Pins 3, 5, 7, 9)			

OE ₂	In	(1113 0, 0, 1, 0)
L	L	Н
L	Н	L
Н	Х	Z

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial Z = High Impedance



Absolute Maximum Ratings(Note 1)

Storage Temperature	$-65^{\circ}C$ to $+150^{\circ}C$
Junction Temperature under Bias	$-55^{\circ}C$ to $+150^{\circ}C$
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	-0.5V to 5.5V
in the HIGH State	–0.5V to $V_{\mbox{\scriptsize CC}}$
Current Applied to Output	
in LOW State (Max)	twice the rated I _{OL} (mA)
DC Latchup Source Current	
(Across Comm Operating Range)	–150 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	$-40^{\circ}C$ to $+85^{\circ}C$
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Param	eter	Min	Тур	Max	Units	V _{cc}	Conditions
VIH	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Vo	Itage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage		2.5			V	Min	$I_{OH} = -3 \text{ mA}$
			2.0			V	Min	$I_{OH} = -32 \text{ mA}$
V _{OL}	Output LOW Voltage				0.55	V	Min	I _{OL} = 64 mA
IIH	Input HIGH Current				1 1	μΑ	Max	$V_{IN} = 2.7V$ (Note 3) $V_{IN} = V_{CC}$
I _{BVI}	Input HIGH Current B	reakdown Test			7	μA	Max	V _{IN} = 7.0V
ΙL	Input LOW Current				-1 -1	μΑ	Max	V _{IN} = 0.5V (Note 3) V _{IN} = 0.0V
V _{ID}	Input Leakage Test		4.75			V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OZH}	Output Leakage Curre	ent			10	μA	0-5.5V	$V_{OUT} = 2.7V; \overline{OE}_n = 2.0V$
I _{OZL}	Output Leakage Curre	ent			-10	μΑ	0-5.5V	$V_{OUT} = 0.5V; \overline{OE}_n = 2.0V$
los	Output Short-Circuit C	urrent	-100		-275	mA	Max	$V_{OUT} = 0.0V$
ICEX	Output HIGH Leakage	Current			50	μA	Max	V _{OUT} = V _{CC}
I _{ZZ}	Bus Drainage Test				100	μΑ	0.0	V _{OUT} = 5.5V; All Others GND
I _{CCH}	Power Supply Current				50	μΑ	Max	All Outputs HIGH
I _{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current				50	μΑ	Max	$\overline{OE}_n = V_{CC};$ All Others at V _{CC} or Ground
I _{CCT}	Additional I _{CC} /Input	Outputs Enabled			1.5	mA		$V_I = V_{CC} - 2.1V$
		Outputs 3-STATE			1.5	mA	Max	Enable Input $V_I = V_{CC} - 2.1V$
		Outputs 3-STATE			50	μΑ	IVIAX	Data Input $V_I = V_{CC} - 2.1V$
								All Others at V _{CC} or Ground
ICCD	Dynamic I _{CC}	No Load				mA/		Outputs Open
	(Note 3)				0.1	MHz	Max	OEn = GND, (Note 4) One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, $I_{CCD} < 0.8 \mbox{ mA/MHz}.$

AC Electrical Characteristics

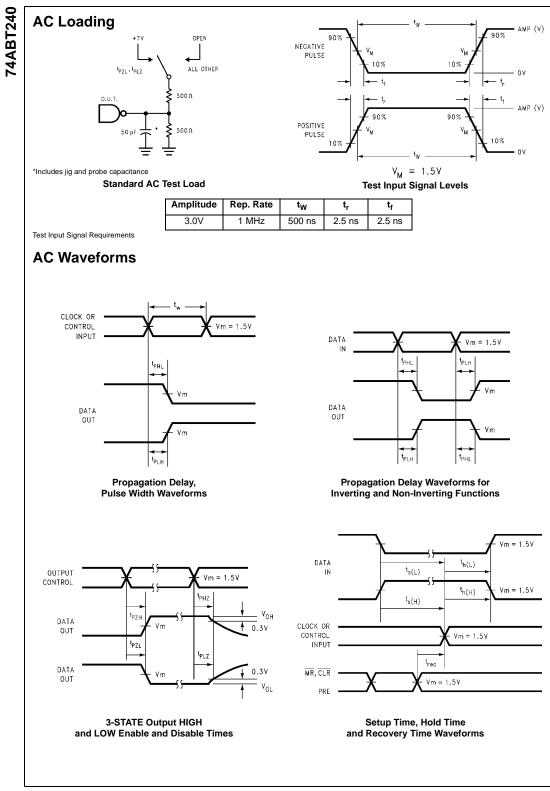
Symbol Parameter		$T_{A} = +25^{\circ}C$ $V_{CC} = +5V$ $C_{L} = 50 \text{ pF}$			$T_{A} = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V - 5.5V$ $C_{L} = 50 \text{ pF}$		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V - 5.5V$ $C_{L} = 50 \text{ pF}$		Units	
		Min	Тур	Max	Min	Max	Min	Max		
t _{PLH}	Propagation Delay	1.0		4.8	0.8	5.5	1.0	4.8	ns	
t _{PHL}	Data to Outputs	1.6		4.8	1.0	5.5	1.6	4.8	115	
t _{PZH}	Output Enable	1.1		6.2	0.8	7.5	1.1	6.2		
t _{PZL}	Time	1.1		6.2	0.8	7.7	1.1	6.2	ns	
t _{PHZ}	Output Disable	1.8		6.4	1.0	7.5	1.8	6.4		
t _{PLZ}	Time	1.6		5.8	1.0	7.2	1.6	5.8	ns	

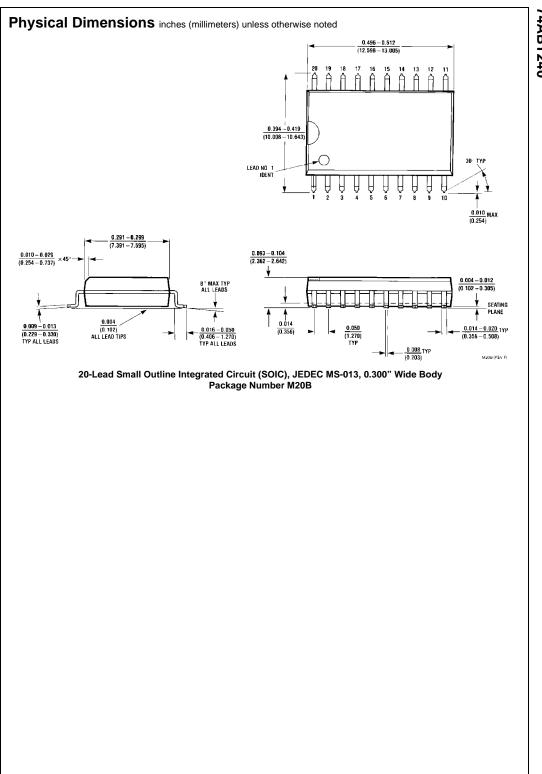
Capacitance

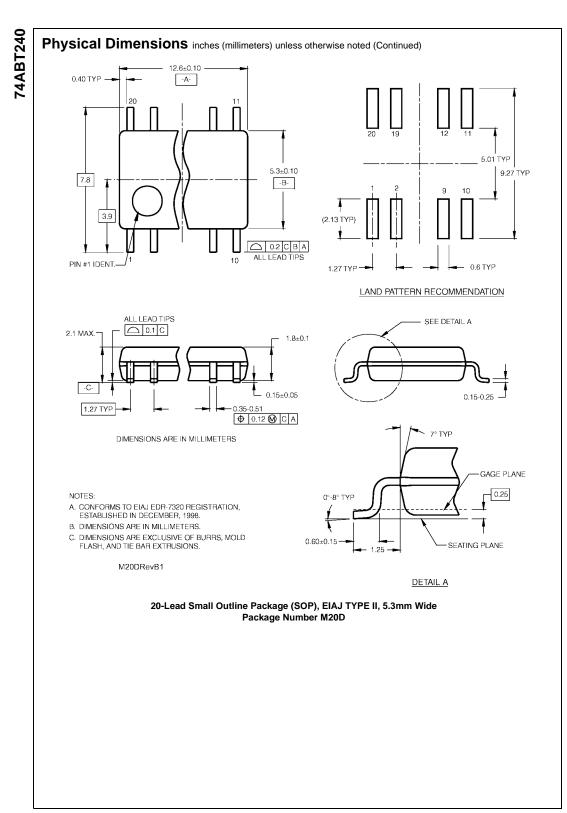
Symbol Parameter		Тур	Units	Conditions T _A = 25°C
CIN	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C _{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

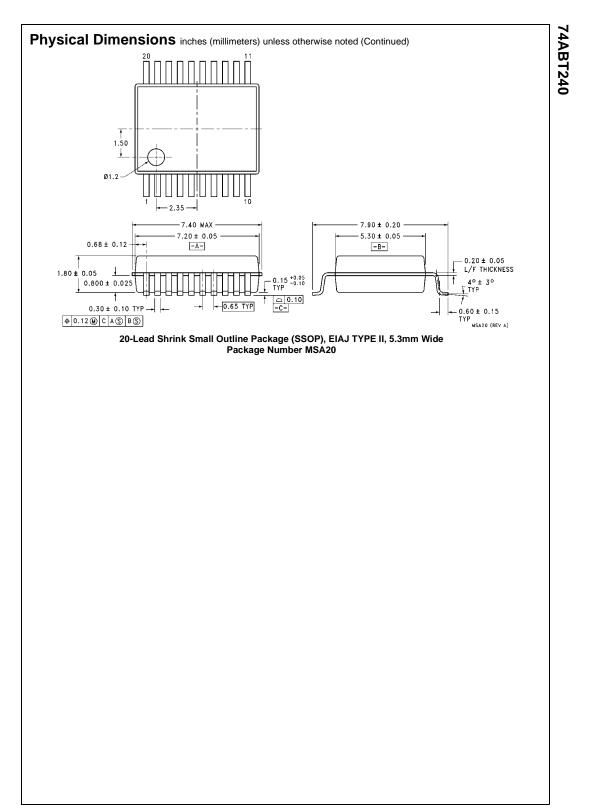
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

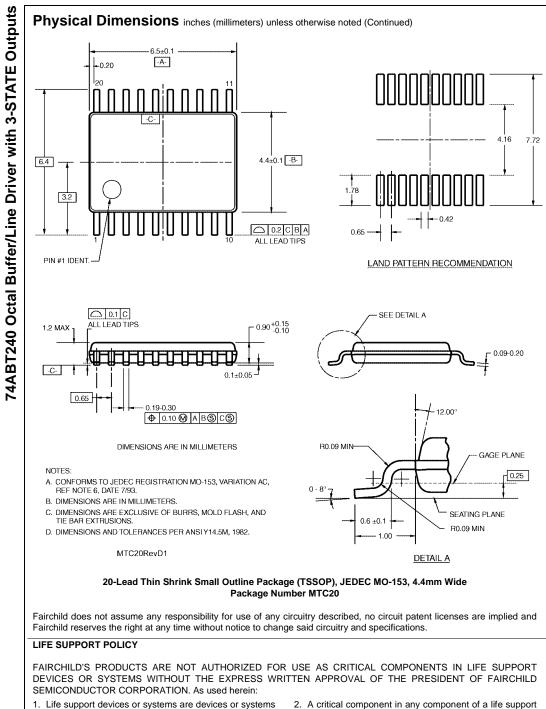
74ABT240











- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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